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Luminescent properties of a new cyan long afterglow phosphor $\text{CaSnO}_3:\text{Lu}^{3+}$

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Persistent luminescence (PPL) materials have gained lots of attention and have been widely used in traffic signs, displays, medical diagnosis and architectural decoration. Single ion doped PPL materials with stable emission are excellent for practical applications, but it is difficult to cover the entire wavelength range. Here, a new cyan long-lasting phosphor $\text{CaSnO}_3:\text{Lu}^{3+}$ was successfully synthesized at 1200 °C by the conventional high temperature solid state method. From the X-ray photoelectron spectroscopy (XPS), it can be concluded that the Sn^{2+} ions exist in the crystal lattice because the doping of Lu^{3+} ions changes the valence state of the Sn ions. According to the thermally simulated luminescence (TSL), the continuous afterglow of $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphors is produced by appropriate hole or electron traps, which are caused by doping the calcium stannate host with rare earth ions (Lu^{3+}). The long-lasting phosphorescence (LLP) properties of the cyan phosphor were first discussed and the afterglow mechanism was expounded in detail. The excitation and the emission spectra of the phosphor revealed the characteristic broad peak of the Sn^{2+} ion. Typical afterglow behavior of the $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphors was exhibited after power was turned off.

1. Introduction

Long afterglow material is a phosphorescent material that can produce visible light for a few seconds or even hours. Due to its unique luminescence properties, it has been made into a series of products, such as luminescent coatings, ceramics, plastics, films, fibers, etc.^{2,3} Currently, more and more reported excellent luminous properties gradually make cyan long afterglow materials meet the requirements of use and are widely used in various fields such as display and energy conversion.

Life and luminous intensity are long-term problems in the study of long afterglow materials. The macroscopic factors affecting these two luminescent properties include the type and content of alkaline earth elements, the type and content of rare earth doping elements, and preparation methods. The experiment adopts high temperature solid phase method, the method is simple, the obtained product has stable performance and good luminescence performance. Unlike ordinary photoluminescent phosphors, long-lasting phosphors (LLP) materials absorb visible light or ultraviolet light, etc., and then store these energies in the crystal lattice and release the stored energy in the form of continuous visible light.⁴ Energy efficiency is high.

Since the discovery of $\text{SrAl}_2\text{O}_4:\text{Eu}^{2+},\text{Dy}^{3+}$ (ref. 5) in 1996, the development of long afterglow (LAG) phosphors was rapid over the past years. A large number of outstanding LAG phosphors have gained considerable commercial value and have been

applied on the various market, including $\text{SrAl}_2\text{O}_4:\text{Eu}^{2+},\text{Dy}^{3+}$ (green), $\text{CaAl}_2\text{O}_4:\text{Eu}^{2+},\text{Nd}^{3+}$ (blue) and $\text{Y}_2\text{O}_3:\text{Eu}^{3+},\text{Ti}^{4+},\text{Mg}^{2+}$ (red).⁶⁻⁸ However, the existing LAG phosphors still face many shortcomings, such as easily deliquescent of aluminates and poor chemical stability of sulfides. Therefore, the materials industry needs to constantly find new substrates that can be used for LAG phosphors. Among the persistent phosphors, cyan phosphors with good LLP properties are rare, far from meeting the needs of market applications. Therefore, it's necessary to create a new cyan long-lasting phosphor to satisfy the growing demand for LLP materials.

Lately, alkaline earth thin oxides (MSnO_3 , M = Sr, Ca, Ba) have attracted lots of concentration in the last years because SnO_4^{2-} anion group is an advantageous candidate for host materials. The CaSnO_3 is more attractive and potent than sulfide as the results of its stable physical and chemical properties, environmental friendliness, simple synthesis process and low cost. Thence, in many cases it's a good choice to use the alkaline earth thin oxides as the matrix for LAG phosphors, such as $\text{CaSnO}_3:\text{Sm}^{3+}$,⁹ $\text{CaSnO}_3:\text{Tb}^{3+}$,¹⁰ $\text{CaSnO}_3:\text{Eu}^{3+}$,¹¹ $\text{Ca}_2\text{SnO}_4:\text{Dy}^{3+}$,¹² $\text{Ca}_2\text{SnO}_4:\text{Er}^{3+}$ (ref. 13) phosphors.

Among the rare earth elements, Lu^{3+} can be used not only as activated ions for upconversion luminescence and ultraviolet emission materials,¹⁴ but also as auxiliary ions, which are served as trap centers to improve LAG performance.¹⁵ As far as existing reports are concerned, there is no report on the phenomenon of Lu^{3+} ions as trap providers. Therefore, it is necessary to do a lot of work to clarify the afterglow characteristics and photoluminescence behavior of $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphors.

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In the research, $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphors were well synthesized. The afterglow behaviors and the luminescence performance of the $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphor were illustrated at length and the mechanism of the long-lasting afterglow of the phosphor was discussed.

2. Experimental

$\text{Ca}_{1-x}\text{SnO}_3:x\% \text{Lu}^{3+}$ ($x = 0, 0.5, 1, 2, 3, 4, 5$) were synthesized by the solid state reaction with SnO_2 (A.R.), Lu_2O_3 (A.R.) and CaCO_3 (A.R.) as raw materials. First, the standard stoichiometric starting materials were uniformly mixed and thoroughly ground in an agate mortar with appropriate ethanol addition for about 30 min.

The resulting material was then compressed into tablets to enhance the synthesis process. The above tablets were required to be compressed into a disc having a diameter of 20 mm and a length of 4 mm (weight 3 g). After holding 1200 °C for 4 hours, the tablets were taken out and ground to obtain the new cyan phosphors.

The excitation and emission spectra were measured by the FLS920 photoluminescence spectrometer to study the luminescence performance of the phosphor. We studied the phase purity of the prepared phosphor samples by TD-3500 X-ray diffractometer (Cu K α , 40 kV and 30 mA). The scanning speed of this process was 0.04, and the range of 2θ was between 10° and 70°. The valence state of the Sn ion is characterized by the X-ray photoelectron spectroscopy (Kratos Axis Ultra DLD) having Al K α radiation. The sample was irradiated with ultraviolet light having a wavelength of 254 nm for 10 minutes, and then the afterglow attenuation curve of the phosphor was measured using FJ427-Al. The TL curve was measured using a FJ427-A1 thermal stimulation spectrometer (Beijing Nuclear Instrument Factory) at a heating rate of 1 K s⁻¹ and a temperature range of 20 °C to 275 °C. All measurements except the TL curve were performed at room temperature standards.

3. Results and discussion

3.1 Phase determination

The phosphor samples were prepared by traditional solid state reaction, with a nominal composition of $\text{Ca}_{1-x}\text{SnO}_3:x\% \text{Lu}^{3+}$ ($x = 0, 0.5, 1, 2, 3, 4, 5$). These phosphors that contained different Lu concentrations were subjected to X-ray diffraction to obtain an XRD pattern as shown in Fig. 1. The figures lead us to the result that although the Lu concentration varies greatly from 0 to 5%, all samples show the same diffraction pattern. Obviously, all diffraction peaks are in good agreement with the standard of CaSnO_3 (JCPDS standard card no. 031-0312), which indicates that it has a perovskite crystal structure with lattice parameters $a = 5.532 \text{ \AA}$, $b = 5.681 \text{ \AA}$, and $c = 7.906 \text{ \AA}$. The phenomenon illustrates that a bit of Lu^{3+} ions have no significant effects on the crystal structure and forms a fine solid solution.

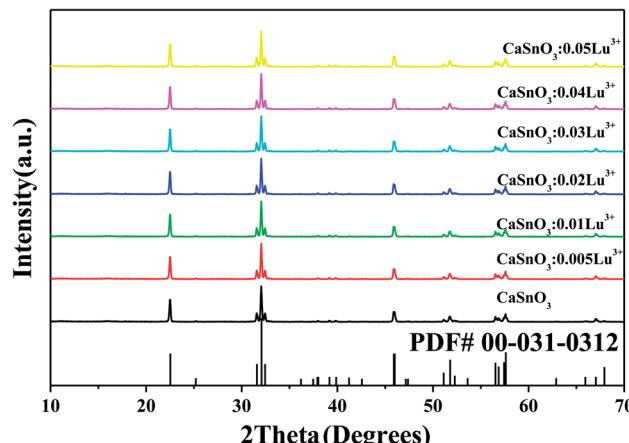


Fig. 1 XRD pattern of the $\text{CaSnO}_3:\text{Lu}^{3+}$ powders with different Lu concentrations.

3.2 Photoluminescent properties

To eliminate the influence of inherent defects that may exist in CaSnO_3 phosphors. CaSnO_3 phosphors without Lu^{3+} were prepared, and related experiments were carried out on the phosphors. After excitation by the UV source, it was observed that the phosphor did not have photoluminescence or afterglow emission. Therefore, we have a reason to believe that the main role of the experiment is due to the doping of Lu^{3+} ions in CaSnO_3 . The peak intensities, which usually correspond to trap concentration, increase until $x = 2.0 \text{ mol\%}$, when it reaches the strongest.¹ Fig. 2 shows the excitation and emission spectra of $\text{CaSnO}_3:2 \text{ mol\% Lu}^{3+}$ phosphor. The excitation spectrum of the $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphor was observed at the emission wavelength of the Sn^{2+} center (496 nm), which showed a relatively wide band. This is due to the singlet transition of the Sn^{2+} center ($S_0 \rightarrow S_1$) with a maximum wavelength of 267 nm.¹⁶ After UV excitation, the Sn^{2+} ions transition from the triplet state to the singlet state ($T_1 \rightarrow S_0$), and the phosphor emits visible light

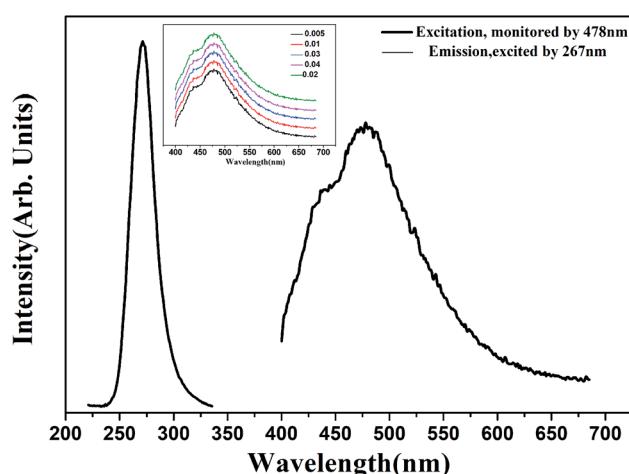


Fig. 2 Excitation and emission spectra of $\text{CaSnO}_3:2 \text{ mol\% Lu}^{3+}$ phosphor, the inset shows emission spectra of $\text{CaSnO}_3:x\% \text{Lu}^{3+}$ ($x = 0.01, 0.02, 0.03, 0.04, 0.05$) phosphors.

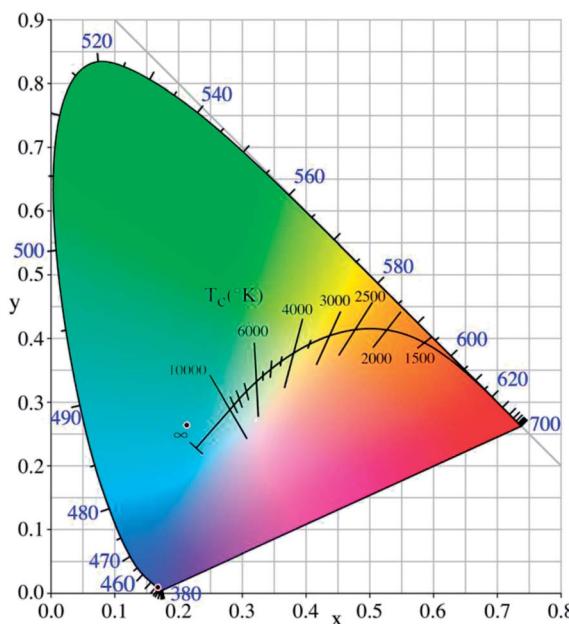


Fig. 3 The CIE 1931 chromaticity coordinates of the CaSnO_3 :2 mol% Lu^{3+} phosphors.

in a wide emission band of 496 nm, as mentioned in other literature.¹⁷ As shown in the inset of Fig. 2, the emission intensity first increases, reaches a maximum peak at the Lu^{3+} concentration of 2 mol%, and then gradually decreases as the Lu^{3+} concentration increases. Therefore, it can be safely said that the optimum doping concentration of Lu^{3+} is 2 mol%. At the same time, owing to the doping of Lu^{3+} ions, Sn^{2+} ions exist in the crystal lattice of CaSnO_3 .

The CIE 1931 diagram achieves the representation of all colors by continuously combining the three primary colors. The method can be used to quantify the tunability of the emission wavelength and the change in the intensity of the emission band. First, the emission spectrum of the prepared CaSnO_3 :2-mol% Lu^{3+} phosphor was converted into the CIE 1931 diagram to calculate x , y chromaticity coordinates. The x , y chromaticity coordinates obtained by the process are shown in the image in

Fig. 3. The value of the chromaticity coordinates (x , y) is calculated to be (0.2131, 0.2643), and the precise emission color of the phosphor can be determined by the coordinates. In the experiment, the x , y chromaticity coordinates of the prepared CaSnO_3 :2 mol% Lu^{3+} phosphor were located in the cyan region, demonstrating the successful synthesis of a new cyan phosphor in this study.

XPS studies were performed to further confirm the presence of Sn^{2+} in the CaSnO_3 : Lu^{3+} phosphor lattice. The results of XPS are shown in Fig. 4(a). From the image we can analyze that the curve of CaSnO_3 : Lu^{3+} phosphor is offset from the CaSnO_3 phosphor. The phenomenon of a slight change in crystal binding energy indicates the presence of divalent tin ions, which may be caused by changes in the valence state of tin ions due to the incorporation of a small amount of Lu^{3+} ions into the crystal lattice. A detailed study of the $\text{Sn} 3d_{5/2}$ XPS peak recorded for CaSnO_3 : Lu^{3+} phosphor is shown in Fig. 4(b). Usually doing this, it is unwrapped into two components, Sn^{2+} and Sn^{4+} . The registered $\text{Sn} 3d_{5/2}$ peak is flooded as a point, and the deconvoluted component is submerged as a solid line. The $\text{Sn} 3d_{5/2}$ binding energy obtained, the full width at half maximum, and the relative areas of each Sn component are listed in Table 1. The main focus of this paper is the relative content of the Sn species, which reveal their respective peaks and relative area. As shown in the experiment, the data indicates that the CaSnO_3 : Lu^{3+} phosphor contains most of the tin in the tetravalent state (99.44%). A small amount of divalent Sn ions are present in the phosphor lattice, which may be due to the doping of Lu^{3+} into the crystal lattice. Therefore, the XPS data supports the presence of Sn^{2+} that is responsible for the PL spectrum (Fig. 2).

Table 1 $\text{Sn} 3d_{5/2}$ binding energy (BE), full-width at half-maximum, and relative area for the different Sn components in the CaSnO_3 : Lu^{3+} phosphor as estimated from the spectrum in Fig. 4

Component	Sn 3d _{5/2}		
	BE/eV	FWHM/eV	Relative area/%
Sn^{2+}	483.62	0.72	56
Sn^{4+}	485.49	1.49	99.44

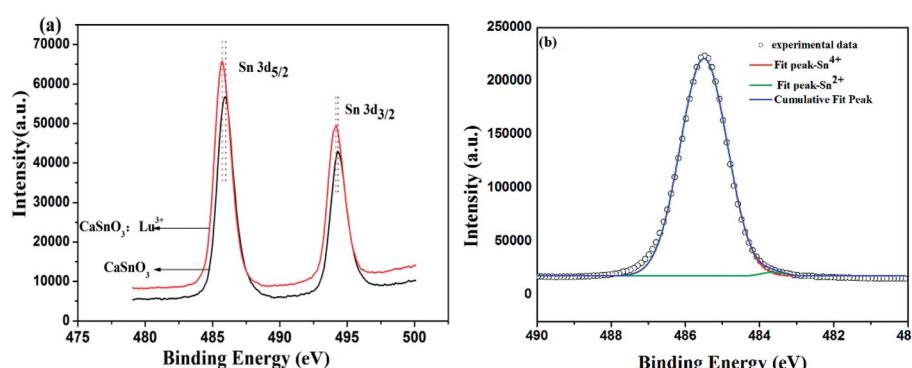


Fig. 4 XPS spectra of the samples CaSnO_3 and CaSnO_3 : Lu^{3+} (a) and registered $\text{Sn} 3d_{5/2}$ XPS peak and spectral deconvolution into different valence states for the CaSnO_3 : Lu^{3+} phosphor (b).

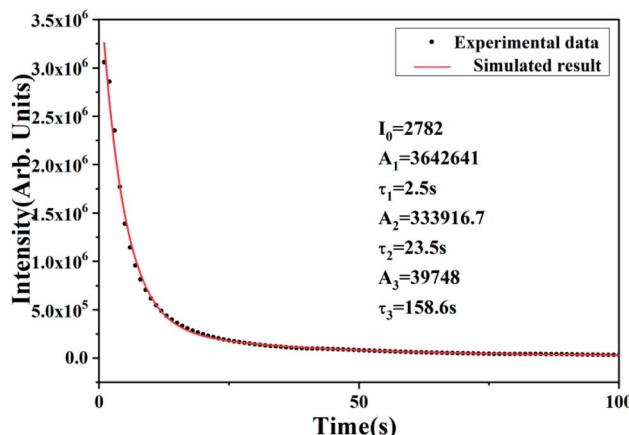


Fig. 5 Afterglow curve of the $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphor.

3.3 Long afterglow properties

The prepared $\text{CaSnO}_3:2$ mol% Lu^{3+} phosphor was tested under switching light conditions, and the phosphor showed a persistent afterglow behavior. A bright cyan afterglow can be observed in the first few minutes, and then the intensity of the luminescence is continuously attenuated. From what has been presented in Fig. 5, it can be found that the initial luminescence attenuation of $\text{CaSnO}_3:\text{Lu}^{3+}$ is faster, but the luminescence decay rate is continuously decreasing, and finally stable emission is achieved.

Although the subsequent luminescence intensity is weak, continuous persistence can still be observed. We have established a three-index afterglow attenuation model for $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphors, which is fully consistent with the behavior of rare earth doped long afterglow phosphors. To further investigate the decay process involved in afterglow behavior, we made the attenuation curve by curve fitting. This attenuation curve can be fitted as follows using a three-exponential equation.^{18,19}

$$I = I_0 + A_1 \exp(-t/\tau_1) + A_2 \exp(-t/\tau_2) + A_3 \exp(-t/\tau_3) \quad (1)$$

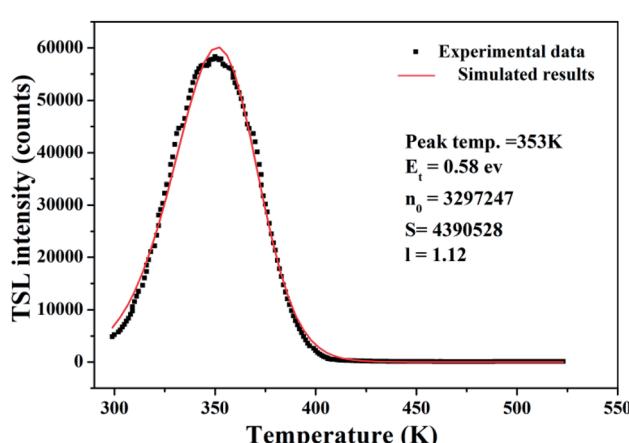


Fig. 6 TSL curve of the $\text{CaSnO}_3:0.02\text{Lu}^{3+}$ phosphor.

I_0 in the equation represents phosphorescence intensity, A_1 , A_2 and A_3 represent constants, and τ_1 , τ_2 , τ_3 represent decay times of three exponential components. The fitting results of the attenuation curve are shown in Fig. 5. By curve fitting, we can infer that the decay time of the phosphor consists of three different exponential components with a maximum value of 156.2 s. Thus, we can conclude that the longer the decay time, the slower the decay rate and the better the afterglow characteristics of the phosphor.

3.4 Thermoluminescence analysis

It is commonly recognized that appropriate trap depth and high trap density play a leading role in LAG performance. We use TSL measurements to explore the relevant information and properties of the traps, resulting in a TSL curve is shown in Fig. 6. The TL spectrum has a single broad peak with no obvious inflection points, indicating no other overlapping peaks. The trap depth and trap density in the phosphor can be obtained by analyzing the TL spectrum using the following equation:^{20–23,25}

$$I(T) = sn_0 \exp\left(\frac{-E}{k_B T}\right) \left[\left(\frac{(l-1)s}{\beta}\right) \int_{T_0}^T \exp\left(-\frac{E}{k_B T'}\right) dT' + 1 \right]^{-l/(l-1)} \quad (2)$$

In the above formula, $I(T)$ represents the TL spectral intensity, s indicates the frequency factor, n_0 means the concentration of trapped charge at $t = 0$, E_t shows the trap level, k_B is the Boltzmann constant, l is the kinetic order, and β is the heating rate, $1 \text{ }^\circ\text{C s}^{-1}$ in this experiment. The parameters s , n_0 , E_t and l can be obtained by empirical TSL shape method²⁴ or by computer fitting technique.²¹ We used a fitting method to obtain the values of the above parameters. For the calculation, the integral in eqn (3) can be expressed as eqn (4):²¹

$$\frac{dn_t}{dt} = \frac{-\alpha n_t^2}{n_t + (b/r)(N - n_t)} \quad (3)$$

$$\int_0^T \exp\left(-\frac{E_t}{kT'}\right) dT' = T \exp\left(-\frac{E_t}{kT}\right) \sum_{j=1}^l \left(\frac{kT}{E_t}\right)^j (-1)^{j-1} j! \quad (4)$$

Considering $j = 3$, we got another expression as eqn (5):

$$\int_0^T \exp\left(-\frac{E_t}{kT'}\right) dT' = T \exp\left(-\frac{E_t}{kT}\right) \left(\frac{kT}{E_t} - 2 \left(\frac{kT}{E_t}\right)^2 + 6 \left(\frac{kT}{E_t}\right)^3 \right) \quad (5)$$

We fit the experimental data according to eqn (1) and (5) and calculate the parameters E_t and n_0 , as listed in Fig. 6. According to previous studies, if the depth of the trap is between 0.4 eV and 0.6 eV, the fluorescent material will exhibit excellent LAG performance. It can be seen from Fig. 6 that the material exhibits excellent afterglow behavior when the trap depth is 0.55 eV, which means that more traps can capture more free electrons and produce brighter initial phosphorescence and longer afterglow duration.^{26,27}

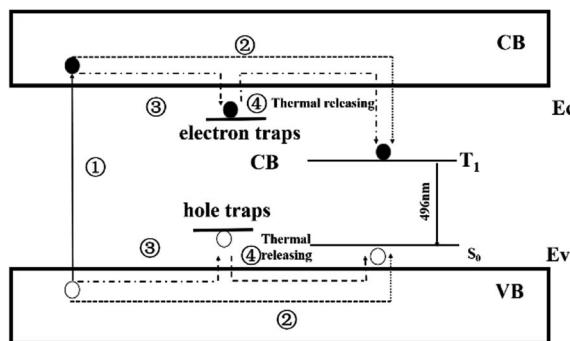
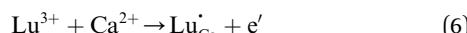


Fig. 7 The schematic graph of persistent luminescence mechanism for $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphor.

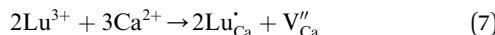
The TL curves as a function of Lu^{3+} are shown in Fig. 6, which clearly presents a peak at 353 K. From the empirical formula $ET = T_m/500$ (ET is the estimated depth with unit of eV and T_m is the temperature at which the TL curve reaches a maximum with a unit of kelvin), we calculated that the trap depth is 0.706 eV.^{1,28}

3.5 Possible mechanism of long afterglow

Derived from the above descriptions and analysis above, we attempt to explain the phosphorescence mechanism of $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphors. In $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphors, Lu^{3+} ions can bind to Ca^{2+} sites because they have very close ionic radii.²⁵ This non-equivalent substitution process occurs in the following equation.



There are two ways to ensure the conservation of charge in the experiment, one is electronic compensation, and the other is vacancy compensation. The first is electronic compensation, which captures the released electrons to maintain charge balance. The element Sn in the phosphor is considered to be a multivalent ion. Therefore, some Sn^{4+} ions may capture electrons released in eqn (5), and the valence state changes from tetravalent to divalent. The substitution of Sn^{2+} for the Sn^{4+} position will result in structural defects, which can be treated as positional locations for charge carrier (electrons) and act as hole traps. The other is vacancy compensation, and the metal ion vacancy generated in the crystal lattice compensates for the charge. Two Lu^{3+} ions will replace three Ca^{2+} ions to balance the charge of these phosphors, resulting in Ca^{2+} vacancy ($\text{V}_{\text{Ca}}^{\prime\prime}$) and positive defects ($\text{Lu}_{\text{Ca}}^{\cdot}$). The defect equation is expressed as follows:



The mechanism of cyan LAG phenomenon in $\text{CaSnO}_3:\text{Lu}^{3+}$ can be interpreted as follows. The structure defects Sn^{2+} and the defects ($\text{V}_{\text{Ca}}^{\prime\prime}$) may act as hole-trapping centers, while $\text{Yb}_{\text{Ca}}^{\cdot}$ as electron trapping centers. In order to clarify the afterglow process more clearly, both Fig. 2 and 7 show schematic diagrams of the phosphorescence mechanism of $\text{CaSnO}_3:\text{Lu}^{3+}$.

Under ultraviolet irradiation (process numbered ①), electrons in VB (valence band) are excited to CB (conduction band) and then transferred to the luminescent center Sn^{2+} through the body. Then, Sn^{2+} is subjected to feature transmission (process numbered ②). At the same time, many photon induced electrons or holes can be captured by electron traps or hole traps (process numbered ③). After the UV light switched off, the trapped electrons and holes can be released with the help of thermal disturbances at the room temperature (process numbered ④). The free electrons will move to the T_1 level of Sn^{2+} and the holes will move to the ground state of Sn^{2+} . At last, electrons recombine with holes and the energy released from the recombination will excite a characteristic emission of Sn^{2+} to generate PPL emission and long afterglow phosphorescence in the $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphor.^{26,27,29,30}

4. Conclusions

In this paper, a new cyan glow afterglow phosphor $\text{CaSnO}_3:\text{Lu}^{3+}$ was successfully prepared by high temperature solid phase method. By observing the PL spectrum and the CIE 1931 chromaticity coordinates, it is concluded that the $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphor emits cyan light due to the triplet to singlet ($T_1 \rightarrow S_0$) transition of the Sn^{2+} ion. XPS measurements showed the presence of Sn^{2+} ions in the crystal lattice, and the relative ratio of $\text{Sn}^{4+}/\text{Sn}^{2+}$ in the $\text{CaSnO}_3:\text{Lu}^{3+}$ phosphor was 3.85. After the illumination source is turned off, long-lasting phosphorescence can be seen in the dark with the naked eye. TSL studies have shown that a suitable electron or hole trap depth is produced by doping Lu^{3+} , which is beneficial for the phosphor to produce long-lasting phosphorescence. At the same time, it was concluded that the LAG phenomenon is caused by the thermal stimulation of holes and electrons escaping from the trap at room temperature.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

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